# NSN 5961-01-245-6236

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ACTOBAS Grou

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## Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

Between 0.250 inches and 0.360 inches

## **Overall Width:**

1.050 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

## Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

### To-204ae

Electrode Internally-electrically Connected To Case:

# Drain

Mounting Method:

Unthreaded hole

## Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 drain to gate voltage and 100.0 drain to source voltage and 20.0 gate to source voltage

### **Current Rating Per Characteristic:**

40.00 amperes drain current

### **Power Rating Per Characteristic:**

150.0 watts total power dissipation

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

### **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

### Unit Of Measure:

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Demilitarization:

No

Fiig:

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